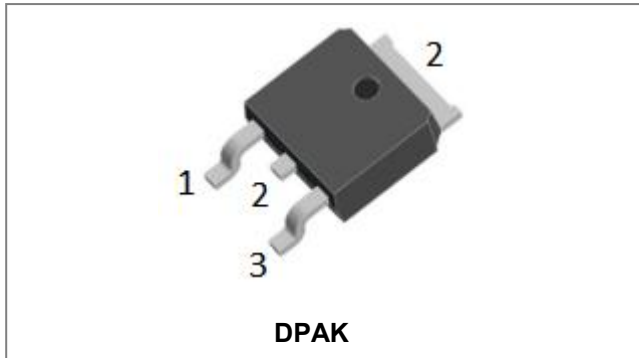


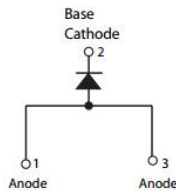
## HD860 ULTRAFAST RECTIFIER



### Features

- Ultra-Fast switching
- High current capability
- Low reverse leakage current
- High surge current capability
- Plastic Material has UL Flammability Classification 94V-0
- This is a Pb – free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

### Circuit Diagram



### Mechanical Data

- Case: Molded Plastic
- Terminals: Plated Leads, Solderable per MIL-STD-202, Method 208
- Weight: 0.39 grams (approx.)
- Mounting Position: Any

### Maximum Ratings and Electrical Characteristics @T<sub>A</sub>=25°C unless otherwise specified

Characteristic	Symbol	HD860	Unit
Peak Repetitive Reverse Voltage	V <sub>RRM</sub>	600	V
Working Peak Reverse Voltage	V <sub>RWM</sub>		
DC Blocking Voltage	V <sub>R</sub>		
RMS Reverse Voltage	V <sub>R(RMS)</sub>	420	V
Average Rectified Output Current @T <sub>A</sub> = 100°C	I <sub>o</sub>	8.0	A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	110	A
Forward Voltage (per element) @I <sub>F</sub> = 8.0A, T <sub>J</sub> =25°C	V <sub>FM</sub>	1.7	V
Peak Reverse Current @T <sub>A</sub> = 25°C	I <sub>RM</sub>	5.0	μA
At Rated DC Blocking Voltage @T <sub>A</sub> = 100°C		50	
Maximum Reverse Recovery Time (Note 1)	T <sub>rr</sub>	50	ns
Max. Voltage Rate of Change	dv/dt	10,000	V/μs
Typical Thermal Resistance Junction to Ambient (Note 2)	R <sub>θJA</sub>	25	K/W
Storage Temperature Range	T <sub>STG</sub> , T <sub>J</sub>	-55 to +150	°C

**Note:** 1. Measured with I<sub>F</sub>=0.5A, I<sub>R</sub>=1.0A, I<sub>rr</sub>=0.25A  
2. Mounted on P.C. Board with 8.0mm<sup>2</sup> lead area

**Ratings and Characteristics Curves**

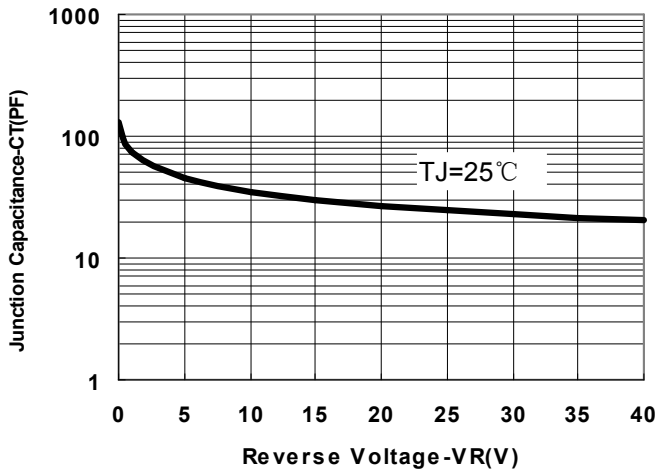


Fig.1-Typical Junction Capacitance

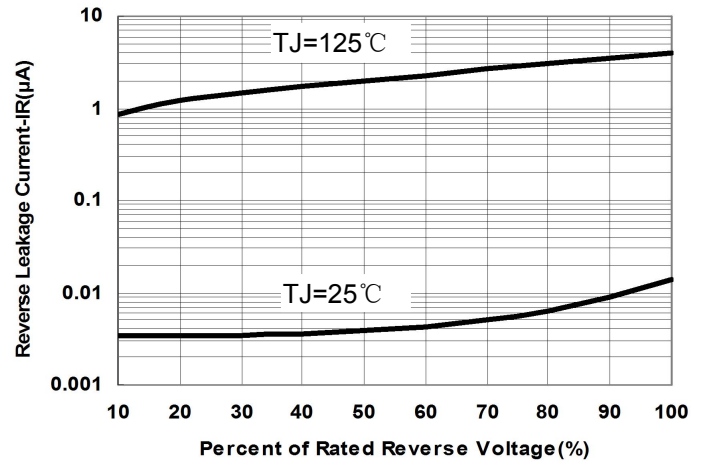


Fig.2-Typical Reverse Characteristics

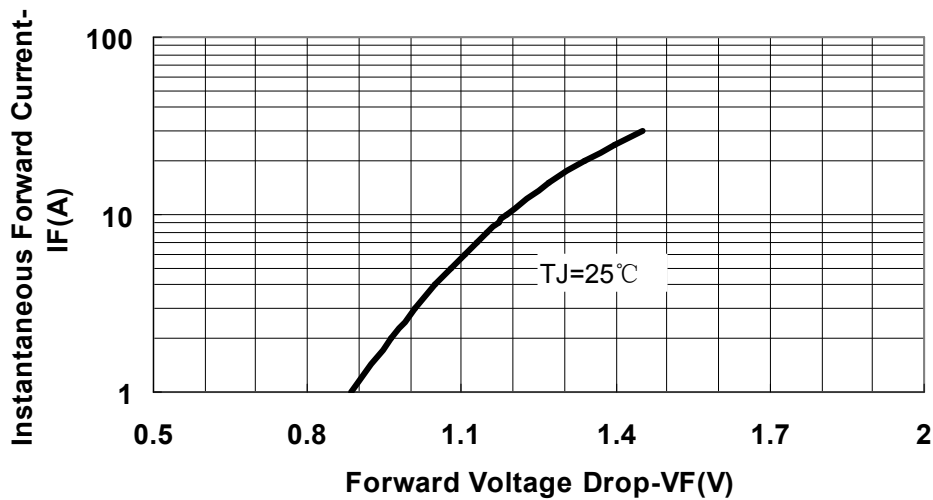
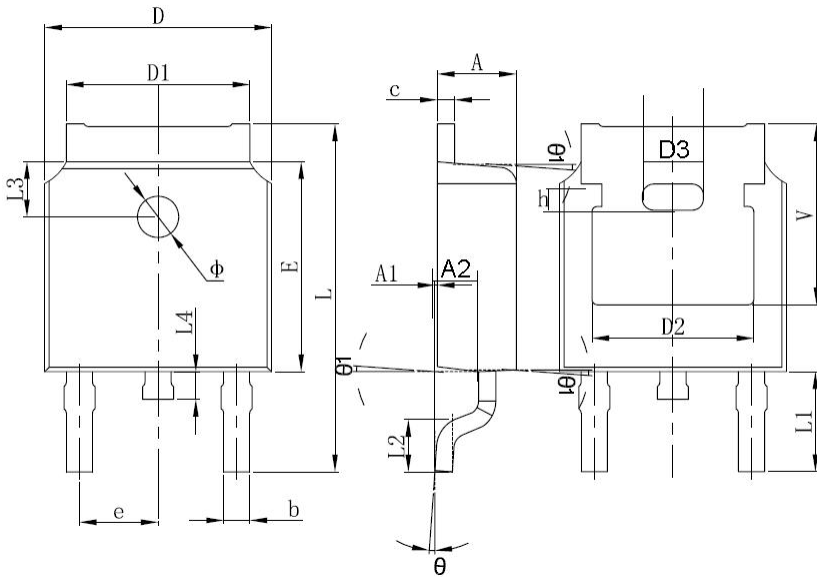


Fig.3-Typical Forward Voltage Drop Characteristics

**Mechanical Dimensions DPAK**



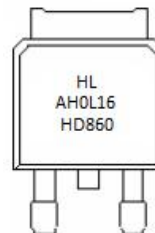
SYMBOL	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	2.20	2.38	0.087	0.094
A1	0.00	0.10	0.000	0.004
b	0.71	0.81	0.028	0.032
c	0.46	0.56	0.018	0.022
D	6.50	6.70	0.256	0.264
D1	5.13	5.46	0.202	0.215
D2	4.83 REF.		0.190 REF.	
E	6.00	6.20	0.236	0.244
e	2.186	2.386	0.086	0.094
L	9.80	10.40	0.386	0.409
L1	2.90 REF.		0.144 REF.	
L2	1.40	1.70	0.055	0.067
L3	1.60 REF.		0.063 REF.	
L4	0.60	1.00	0.024	0.039
Φ	1.10	1.30	0.043	0.051
Θ	0°	8°	0°	8°
A2	0.91	1.11	0.036	0.044
V	5.35 REF.		0.211 REF.	
D3	1.778 REF.		0.070 REF.	
h	0.762 REF.		0.030 REF.	
Θ1	7°		7°	

**Ordering Information**

Device	Package	Shipping
HD860	DPAK (Pb-Free)	2500pcs / reel

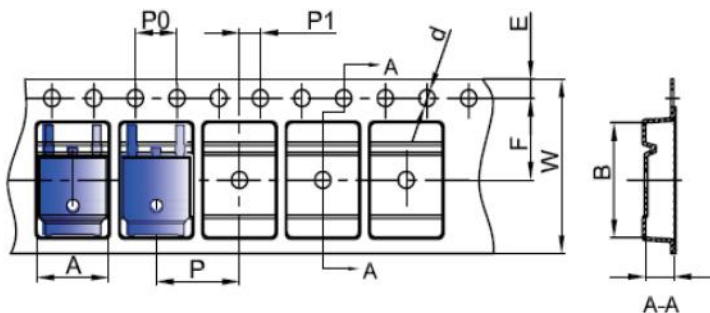
For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

**Marking Diagram**



1<sup>st</sup> row HL  
2<sup>nd</sup> row AH0L16  
3<sup>rd</sup> row HD860  
Where XX is Determined by customer

**Carrier Tape & Reel Specification DPAK**



SYMBOL	Millimeters	
	Min.	Max.
A	6.80	7.00
B	10.40	10.60
C	2.60	2.80
d	Φ1.45	Φ1.65
E	1.65	1.85
F	7.40	7.60
P0	3.90	4.10
P	7.90	8.10
P1	1.90	2.10
W	15.90	16.30

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